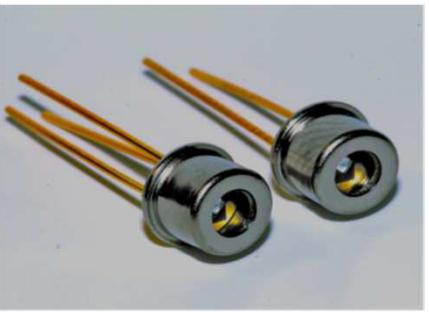


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Spectral range	Type	Case
visible-near IR	Si	TO-46, glass window cap

Circular ($\varnothing 230 \mu\text{m}$) 0.04 mm^2 active area avalanche photodiode optimized sensitivity at 905 nm, housed in a hermetic TO-46 metal can package. It is well suited for applications requiring high speed and low noise in visible-near IR applications.	
Features: <ul style="list-style-type: none"> > Fast Rise Time > Ultra Low Noise > Low Capacitance > High Gain > Optimum Gain M100 Applications: <ul style="list-style-type: none"> > Optical rangefinders > High speed optical communications > Medical Equipment > Bar Code Readers 	

Absolute maximum ratings

Parameters	Symbol	Rating	Unit
Operating temperature range	T_{OPR}	-20...+85	°C
Storage temperature range	T_{STG}	-55...+125	°C
Power dissipation	P_D	1	mW
Storage temperature range	I_F	1	mA
Operating voltage	V_{OP}	$0.95 \times V_{BR}$	V
Lead soldering temperature*	T_{LS}	260	°C

*Time 10 sec max


Electro-optical characteristics:
 $T_{amb}=25^\circ\text{C}$, unless otherwise specified

Parameters	Symbol	Min	Typ	Max	Unit	Test conditions
Sensitivity range	λ	400		1100	nm	
Active area	I_{PH}		$\varnothing 230$		μm	
Responsivity	S_λ	50	55		A/W	$\Phi_e=1 \mu\text{W}$, $M=100$, $\lambda=905 \text{ nm}$
Rise time	t_R		0.6		ns	$f=1 \text{ MHz}$, $R_L=50 \Omega$, $\lambda=905 \text{ nm}$
Dark current	I_D	0.1	0.2	1	nA	$M=100$
Capacitance	C_j		1		pF	$M=100$, 1 MHz
Optimal gain	M		100			
Breakdown voltage	V_{BR}	160		200	V	$I_R=2 \mu\text{A}$
Temperature coefficient	TKV		0.9		V/K	$T=-40...+85$

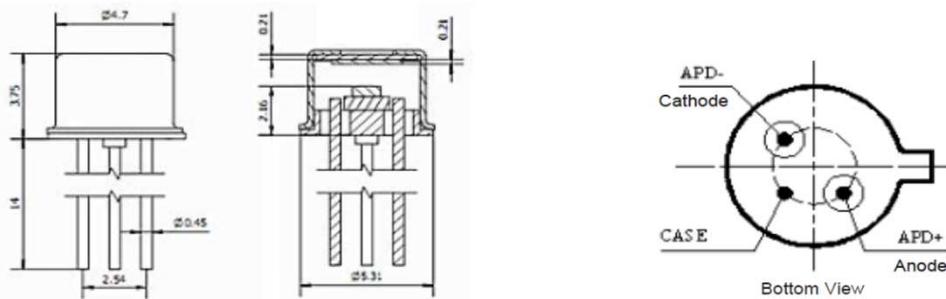
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Unit: mm, Tolerance: ± 0.2

Package dimensions in mm

Fig 1 Responsivity, $V_r=0V$

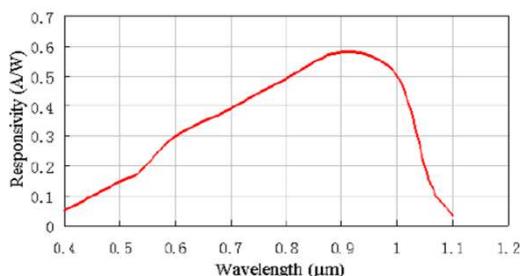


Fig 2 Dark Current

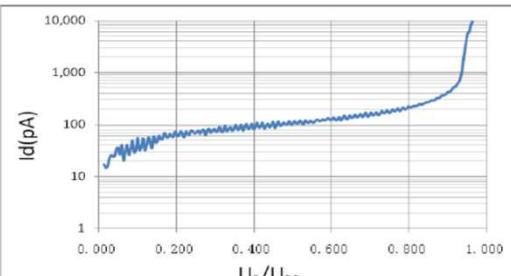


Fig 3 Multiplication

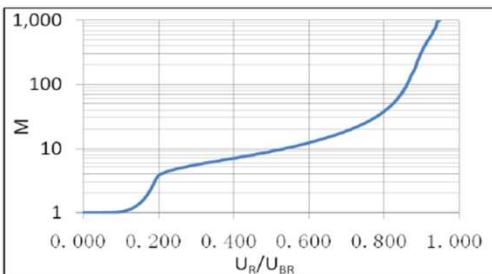
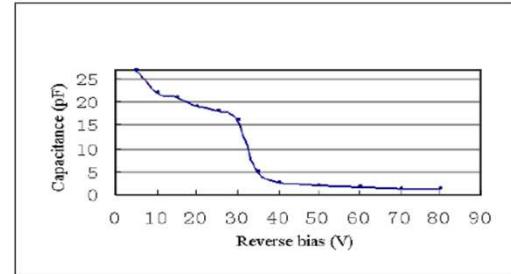


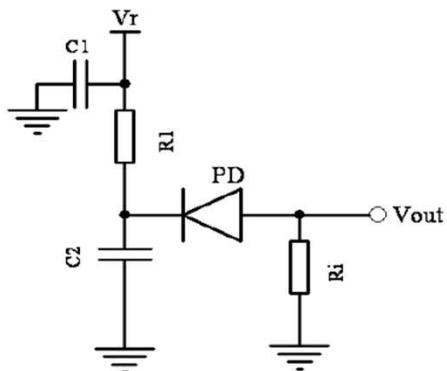
Fig 4 Capacitance



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Applications Diagram

Notes: C1 - Filter capacitor, filter noise from Vr.

C2 - bypass capacitor, the loop to ground for AC signal.

R1 - current-limiting resistor, protect APD from higher voltage.

Ri - sampling resistor, convert the current signal into a voltage signal.

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We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer.